PULSED POWER SYSTEM 脈衝功率系統



Po-Yu Chang

Institute of Space and Plasma Sciences, National Cheng Kung University

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Tuesday 9:10-12:00

Lecture 11

http://capst.ncku.edu.tw/PGS/index.php/teaching/

Online courses:

https://nckucc.webex.com/nckucc/j.php?MTID=md577c3633c5970f80cbc9e8 21927e016

^{2023/11/28} updated 1

Many MOSFET connected in series can be used to provide a fast high-voltage triggering pulse



Pulse generator by stacking power MOSFETs



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Pulse generator by stacking power MOSFETs



R. J. Baker and B. P. Johnson, Rev. Sci. Instrum. 63, 5799 (1992)

Pulse generator by stacking power MOSFETs





Switches

- Closing switches: the switching process is associated with voltage breakdown across an initially insulant element.
- Opening switches: the switching process is associated with a sudden growth of its impedance.

Pulse-forming lines

Blumlein line

- Pulse-forming network
- Pulse compressor
- Pulse transmission and transformation



- A constant-voltage plateau is needed for many pulsed-power applications.
- Various arrangements of LC elements are necessary. It is called "Pulse-Forming Networks (PFN)".



- Transmission lines are the continuous borderline case of a network consisting of discrete LC elements.
- Depending on the time T during which energy is extracted from or supplied to the element, a transmission line can be described as lumped circuit element or an extended object.
 - T > T_{travel}, the time it takes for an EM wave to move from one terminal of the element to the next \rightarrow lumped circuit element.
 - T < T_{travel}, the time it takes for an EM wave to move from one terminal of the element to the next \rightarrow Transmission line.



Different kinds of transmission line and the inductance and the capacitance per unit



1. Coaxial transmission line:

$$C' = 2\pi\varepsilon/\ln(r_{\rm o}/r_{\rm i})$$
$$L' = (\mu/2\pi)\ln(r_{\rm o}/r_{\rm i})$$
$$Z_0 = \left((\mu/\varepsilon)^{1/2}/2\pi\right)\ln(r_{\rm o}/r_{\rm i})$$
$$= 60(\mu_{\rm r}/\varepsilon_{\rm r})^{1/2}\ln(r_{\rm o}/r_{\rm i})$$

2. Double-wire line:

$$C' = \pi \varepsilon / \operatorname{arcosh}(D/d)$$
$$L' = (\mu/\pi) \operatorname{arcosh}(D/d)$$
$$Z_0 = \left((\mu/\varepsilon)^{1/2}/\pi\right) \operatorname{arcosh}(D/d)$$

3. Parallel-plate line:

$$C' = \varepsilon D/d$$

$$L' = \mu d/D$$

$$Z_0 = (\mu/\varepsilon)^{1/2} (d/D)$$

4. Stripline:

$$C' = 2\varepsilon D/d$$
$$L' = \mu d/2D$$
$$Z_0 = (\mu/\varepsilon)^{1/2} (d/2D)$$





- Resistances per unit length: $R'_1 + R'_2 \rightarrow R' \rightarrow R$.
- Conductance per unit length: $G' \rightarrow G$.
- All quantities are frequency-dependent because of the skin effect and because the dielectric constant depends on the frequency.
- Assume that they are independent of the position x, the voltage V and current I.



 $\frac{d}{\mathrm{dt}} \to p$

dx

 $\widetilde{\mathsf{d}I}$

dx

$$\int \frac{U' - U}{dx} \equiv \frac{\partial U}{\partial x} = -RI - L\dot{I}$$
$$\frac{I' - I}{dx} \equiv \frac{\partial I}{\partial x} = -GU - C\dot{U}$$



• Laplace transform:
$$x = x e^{pt}$$
,

 $\frac{\mathrm{d}U}{\mathrm{d}x} = -R\widetilde{I} - pL\widetilde{I} = -(R + pL)\widetilde{I}$ $\frac{\mathrm{d}\widetilde{I}}{\mathrm{d}x} = -G\widetilde{U} - pC\widetilde{U} = -(G + pC)\widetilde{U}$

• Lossless line where R=0, G=0:

$$\frac{d^{2}\widetilde{U}}{dx^{2}} = -(R + pL)\frac{d\widetilde{I}}{dx} = (R + pL)(G + pC)\widetilde{U}$$
$$\frac{d^{2}\widetilde{I}}{dx^{2}} = -(G + pC)\frac{d\widetilde{U}}{dx} = (G + pC)(R + pL)\widetilde{I}$$
$$\widetilde{U}$$

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Lossless line where R=0, G=0:

$$\frac{d^{2}\tilde{U}}{dx^{2}} = p^{2}LC\tilde{U}$$

$$\frac{d^{2}\tilde{I}}{dx^{2}} = p^{2}LC\tilde{I}$$

$$U(x,p) = U_{x}(p) = \begin{cases} \tilde{U}_{+}e^{-p\sqrt{LC}x} \\ \tilde{U}_{-}e^{p\sqrt{LC}x} \end{cases}$$
Inverse Laplace transform:

$$L\{U_{x}(t-\tau)\} = \tilde{U}e^{-pt}$$

 $U(x,t) = U_x(t) = \begin{cases} U_+(t - x\sqrt{LC}) \\ U_-(t + x\sqrt{LC}) \end{cases}$

or Linear combination:

.

$$\boldsymbol{U}_{\boldsymbol{X}}(\boldsymbol{t}) = \boldsymbol{U}_{+} \left(\boldsymbol{t} - \boldsymbol{X} \sqrt{\mathrm{LC}} \right) + \boldsymbol{U}_{-} \left(\boldsymbol{t} + \boldsymbol{X} \sqrt{\mathrm{LC}} \right)$$

$$\boldsymbol{U}(\boldsymbol{x},\boldsymbol{t}) = \boldsymbol{U}_{\boldsymbol{x}}(\boldsymbol{t}) = \begin{cases} \boldsymbol{U}_{+}(\boldsymbol{t} - \boldsymbol{x}\sqrt{\mathrm{LC}}) \\ \boldsymbol{U}_{-}(\boldsymbol{t} + \boldsymbol{x}\sqrt{\mathrm{LC}}) \end{cases}$$



or Linear combination:

 \sim

$$\boldsymbol{U}_{\boldsymbol{x}}(t) = \boldsymbol{U}_{+} \big(t - \boldsymbol{x} \sqrt{\mathrm{LC}} \big) + \boldsymbol{U}_{-} \big(t + \boldsymbol{x} \sqrt{\mathrm{LC}} \big)$$

$$\frac{dU}{dx} = -pL\tilde{I} \qquad \mp p\sqrt{LC}\tilde{U}_{\pm} = -pL\tilde{I}_{\pm}$$

$$\frac{\tilde{U}_{+}}{\tilde{I}_{+}} = -\frac{\tilde{U}_{-}}{\tilde{I}_{-}} = \sqrt{\frac{L}{c}} \equiv Z_{0} \qquad Z_{0} = \frac{U_{+}(t - x\sqrt{LC})}{I_{+}(t - x\sqrt{LC})} = -\frac{U_{-}(t + x\sqrt{LC})}{I_{-}(t + x\sqrt{LC})}$$

$$Transmission line$$

$$\psi_{-} = \frac{1}{\sqrt{LC}} \qquad \psi_{+} = \frac{1}{\sqrt{LC}}$$

Termination of arbitrary freq-dependent impedance Z(p)

• Lossless transmission line terminates with an arbitrary freq-dependent impedance Z(p) in Laplace space.



Termination of arbitrary freq-dependent impedance Z(p)



Pulse is reflected when there is an impedance mismatch

$$W_{1-,I_{1-}} \qquad \underbrace{U_{1+,I_{1+}}}_{Z_{01}} \qquad \underbrace{U_{2+,I_{2+}}}_{Z_{02}} \qquad for equation is solved as the equation is solved$$

• For impedance match, i.e., $Z_{01}=Z_{02}$: $\rho = 0$ T = 1

- Reflection-free junction: $Z_{01}=Z_{02}$ is necessary but not sufficient.

• If the geometry of a line changes arbitrary, it becomes impossible to satisfy Maxell's equation just by superposing the fundamental waves.

Smooth transition is required

 Only by a smooth transition can we achieve the condition that the fields are not disturbed too much so that the reflections can be avoid for high frequency.



Only half of charged voltage is provided in a basic pulse forming line (PFL)



¹⁹

Blumlein pulse forming line (PFL)



















A Blumlein line can be built by using two coaxial transmission line



 Example: RG58 coaxial cable, 50 Ω, V_{signal}~2x10¹⁰ cm/s => L=10 cm, Δt=1 ns.

Coaxial Blumlein line







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A simple pulsed-power system is a RLC circuit



Pulse-forming network (PFN)



Equivalent Guillemin Networks







Pule-forming LC chain



Fig. 5.11. Pulse-forming LC chain

The current output of a LC circuit is a basis of Fourier series


A trapezoidal wave can be expressed by Fourier series (Guillemin's method)



The required inductance and capacitance are obtained by comparing LC output with the Fourier series



A trapezoidal current output can be generated using Guillemin's pulse-forming networks



Fourier components of τ =1 ms, a=0.1



n	#/
b1	1.2524
b3	0.3643
b5	0.1621
b7	0.069
b9	0.0155

Coils with 8 turns and a PFN charged to 1 kV will be used



l (kA)	V (kV)		1	2	3	4	5	E (kJ)	% to 100 J
20	2	L(uH)	25.4	26.1	39.3	68.0	228.7	9.0	1.1 %
		C(uF)	3986.5	386.5	103.2	30.4	5.5		
20	1	L(uH)	12.7	14.6	19.6	34.0	114.4	4.5	2.2 %
		C(uF)	7973.0	773.1	206.4	60.9	10.9		
2.5	2	L(uH)	203.3	233.0	314.2	543.7	1830.0	1.1	8.9 %
		C(uF)	498.3	48.3	12.9	3.8	0.7		
2.5	1	L(uH)	101.7	116.5	157.1	271.8	915.0	0.6	17.7 %
		C(uF)	996.6	96.6	25.8	7.6	1.4		

A square pulse with a flat top of 2.5 kA can be generated





A simple PFN with constant C and L in all stages can also be used



$$C \equiv \bar{C} = \frac{1}{N} \sum_{n=1}^{N} C_n = 225 \mu F$$
$$L_n = 2nL + L_L \approx 2nL$$
$$\omega_n = \frac{1}{\sqrt{L_n C}} \approx \frac{1}{\sqrt{2nLC}}$$

• For 5 stages:

$$\omega_5 = \frac{2\pi}{T} = \frac{\pi}{\tau} = \frac{\pi}{1\text{ms}}$$
$$L = 45\mu\text{H}$$



The energy coupling efficiency is lower using the simple PFN



Only 4.4 % of the energy is transferred to magnetic energy.

Mini-spherical tokamak



A square pulse of 2.5-kA current output with duration of 1 ms can be provided



The actual components were determined by what we could get





Discharge current measurements



Resistant played an important role



Stage	C (theory)	L (theory)	L (measure)	R (measure)
1	990 (uF)	102.8 (uH)	132 <u>+</u> 4 (uH)	0.28 <u>±</u> 0.01 (Ω)
2	100 (uF)	114.9 (uH)	123 <u>±</u> 0.4 (uH)	0.32 <u>±</u> 0.02 (Ω)
3	25 (uF)	157 (uH)	158 <u>+</u> 1 (uH)	0.43 <u>±</u> 0.01 (Ω)
4	7.5 (uF)	270 (uH)	277 <u>+</u> 7 (uH)	0.73±0.03 (Ω)









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Pulse compressor

Pulse transmission and transformation

- Pulse compression scheme: a charged capacitor can transfer almost all of its energy to an uncharged capacitor if connected through an inductor.
- Output voltage can be doubled in a peaking circuit.



Capacitor load



 $I = \alpha sin(\omega t) + \beta cos(\omega t)$

Capacitor load

~1

$$I = \alpha \sin(\omega t) + \beta \cos(\omega t)$$

$$I(t = 0) = 0 => \beta = 0$$

$$I = \alpha \sin(\omega t)$$

$$\frac{dI}{dt} = \alpha \omega \cos(\omega t)$$

$$L_M \frac{dI}{dt}\Big|_{t=0} = L_M \alpha \omega = V_M \qquad \alpha = \frac{V_M}{L_M \omega}$$

$$I(t) = \frac{V_M}{L\omega} \sin(\omega t)$$

$$V_1 = V_M - \frac{1}{C_M} \int_0^t \frac{V_M}{L\omega} \sin(\omega t) dt = V_M - \frac{V_M C_2}{C_M + C_2} [1 - \cos(\omega t)]$$

$$V_2 = \frac{1}{C_2} \int_0^t \frac{V_M}{L\omega} \sin(\omega t) dt = \frac{V_M C_M}{C_M + C_2} [1 - \cos(\omega t)] \qquad \frac{V_2}{V_M}\Big|_{max} = \frac{2C_M}{C_M + C_2}$$
for $C_2 \sim C_M, \frac{V_2}{V_M} \sim 1$

or all

Pulse compression scheme: C₂~C_M



$$V_1 = V_M - \frac{V_M C_2}{C_M + C_2} [1 - \cos(\omega t)] \approx V_M - \frac{V_M}{2} [1 - \cos(\omega t)]$$

$$V_2 = \frac{V_M C_M}{C_M + C_2} [1 - \cos(\omega t)] \approx \frac{V_M}{2} [1 - \cos(\omega t)]$$

For $t = \frac{\pi}{\omega}$, $V_1 \approx 0$, $V_2 \approx V_M$

Water is commonly used as the dielectric material for the intermediate capacitor

$$C = \frac{2\pi\epsilon_r\epsilon_0}{\ln(b/a)}l \qquad \text{For } \frac{b}{a} = \frac{1}{0.9} \approx 1.1$$

• The gap between two cylinders need to be able to handle the high voltage.

Air:
$$\epsilon_r = 1 => \frac{C}{l} = 0.5 \times 10^{-9} F/m$$

Water:
$$\epsilon_r = 80 => \frac{C}{l} = 4 \times 10^{-8} F/m$$



Ex: KALIF, bipolar Marx generator, charged up to ± 100 kV. V_{M,out}=5 MV.

$$C_M = \frac{0.5\mu\mathrm{F}}{25} = 25\mathrm{nF}$$

Using air: $l = \frac{25 \times 10^{-9}}{0.5 \times 10^{-9}} = 50 \text{ m}$

Using water: $l = \frac{25 \times 10^{-9}}{4 \times 10^{-8}} = 0.625 \text{ m}$

Intermediate storage capacitors can be used to compress the pulse



Marx bank

intermediate storage capacitors

pulse forming lines water-insulated insulator outer simulation transmission stack MITLs volume lines



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Insulating interface separating the vacuum section and the liquid dielectric is needed

- Some tasks in science and technology required brightness of intense pulsed radiation > 100 TW/cm²-Sr. With E > 1 MJ, electric power > 100 TW, electric power flux density > 100TW/m² are needed.
- Vacuum environment is required.
- High-voltage pulse must enter a vacuum vessel hosting the source through an insulating interface separating the liquid dielectric from the vacuum section.



The interface consists of insulating rings separated by metallic grading rings

- The metal grading rings are used to distribute the potential homogeneously over the interface on the vacuum surface.
- The metallic and dielectric rings are sealed to hold the high vacuum either by O-rings or by Metal-to-dielectric bond.
- Sparking on the surface on the vacuum side is more important.
- Electrons may be produced by field emission on metallic surfaces.



The side surface of the dielectric material is tilted to prevent flash over



• Electron avalanches may occur with the tangential electric field from the space charge on insulator.



 Dielectric-vacuum interface is the weakest element of a high-voltage pulse line under E-field stress.

$$E_{\rm DB} = \frac{7 \times 10^5}{t^{1/6} A^{1/10}} (V/m)$$

- t: time when $E > 87\% E_{max}$.
- For t=10 ns, E_{max}=20MV/m, Max power density that can be delivered is 1 TW/m².

Self-magnetic insulation



- For E > 20 MV/m, homogeneous plasma layer is generated within a few nanosecond.
- For I > I_{crit}, electron orbits can no longer reach the anode => more and more sections are insulated. => An electron sheath forms on the negative conductor.

Electromagnetic shock wave is formed



Distance from pulse front (m)

Pulse transformers



- High-voltage transformers: used for transformation of current, voltage, impedance, polarity inversion, insulation and coupling between circuits at different potentials.
- Based on magnetic coupling between two conducting circuits.
- Perfect or ideal transformer: no ohmic losses, no eddy currents, without hysteresis and stray field => magnetic flux goes completely through both the primary and second coil.
- Faraday's law:

$$U_{1} = N_{1} \frac{d\phi}{dt}$$
$$U_{2} = -N_{2} \frac{d\phi}{dt}$$
$$\frac{U_{2}}{U_{1}} = -\frac{N_{2}}{N_{1}}$$



The transformer rise the voltage but reduce the current

$$U_1 = N_1 \frac{d\Phi}{dt} \qquad \frac{U_2}{U_1} = -\frac{N_2}{N_1}$$
$$U_2 = -N_2 \frac{d\Phi}{dt}$$

 For open circuit, i.e. secondary coil is open => φ is caused by *i*₁ only:

$$i_{10} = \frac{U_1}{\mathrm{i}\omega\mathrm{L}_1}$$



• If a load of complex impedance Z is connected to the secondary coil:

 $i_2 = \frac{U_2}{Z}$ $N_2 i_2 = N_1 i_1'$ Additional flux from the secondary coil is compensated from primary coil.

$$i_1' = i_{10} + i_1' = i_{10} - \frac{N_2}{N_1}i_2$$
 Power $= (i_1' - i_{10})U_1 = -\frac{N_2}{N_1}i_2U_1 = i_2U_2$
If $i_{10} << \frac{N_2i_2}{N_1} => i_1 = -\frac{N_2}{N_1}i_2$

Rectifier



https://zh.wikipedia.org/wiki/%E6%95%B4%E6%B5%81%E5%99%A8

Full-wave rectifier with smoothing capacitor



https://electronics.stackexchange.com/questions/363454/smoothing-a-full-wave-rectifier-voltage

Dual output

• Positive cycle:



• Negative cycle:





Voltage multiplier (Cockcroft–Walton (CW) generator)



Voltage multiplier (Cockcroft–Walton (CW) generator)



Ζ4

Vi

C2

Dual-output







Internal of a magnetron



https://kids.britannica.com/students/article/electron-tube/106024/media?assemblyId=137

Magnetron is a forced oscillation driven by electrons between the gap



http://hyperphysics.phy-astr.gsu.edu/hbase/Waves/magnetron.html 72
Magnetron schematic diagram



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Magnetron schematic diagram



Magnetron schematic diagram



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Pulse generator using H-bridge inverter



Pulse generator using H-bridge inverter



Pulse generator using H-bridge inverter



Pulse generator using DC power supply



Pulse generator



High-frequency switch mode power supply



Currents with specific profiles needed to be provided to drive coils in Tokamaks to confine the plasma



Radius R [m]

An H-bridge combining pulse width modulation technique will be used to provide the controllable currents

- H-bridge configuration provides the capability of reversing the current direction:
- Pulse width modulation provides the capability of controllable currents



M. Agredano-Torres, etc., Fusion Eng. Des. **168**, 112683 (2021) C. Boonmee and Y. Kumsuwan, 2012 15th International Power Electronics and Motion Control Conference, Novi Sad, Serbia, 2012, pp. LS8c.3-1

The output voltage is controlled by the status of switches S1~S4





- S_1/S_2 ON; S_3/S_4 Off: $V_{AB} = V_d$.
- S_1/S_2 Off; S_3/S_4 ON: $V_{AB} = -V_d$.
- $S_1/S_2 ON; S_3/S_4 ON: V_{AB} = 0.$

A. Namboodiri & H. S. Wani, I. J. Innovative Research in Sci. & Tech. 1, 2349 (2014)

Bipolar Modulation Scheme



A. Namboodiri & H. S. Wani, I. J. Innovative Research in Sci. & Tech. 1, 2349 (2014)

Unipolar Modulation Scheme



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Simulation using bipolar modulation scheme



Simulation using bipolar modulation scheme

